

## N-Channel Super Junction Power MOSFET $\, \mathrm{I\!V}$

## **General Description**

The series of devices use advanced trench gate super junction technology and design to provide excellent RDS(ON) with low gate charge. This super junction MOSFET fits the industry's AC-DC SMPS requirements for PFC, AC/DC power conversion, and industrial power applications.

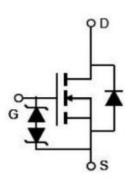
#### **Features**

- Optimized body diode reverse recovery performance
- ●Low on-resistance and low conduction losses
- Small package
- ●Ultra Low Gate Charge cause lower driving requirements
- ●100% Avalanche Tested
- ●ROHS&Halogen compliant

### **Application**

- Power factor correction (PFC)
- Switched mode power supplies(SMPS)
- Uninterruptible Power Supply (UPS)
- LLC Half-bridge

| V <sub>DS min@Tjmax</sub> | 650  | V  |
|---------------------------|------|----|
| R <sub>DS(ON)TYP</sub> .  | 380  | mΩ |
| $I_D$                     | 10   | Α  |
| Qg                        | 13.7 | nC |



## Schematic diagram

♦ Intrinsic fast-recovery body diode

**Package Marking And Ordering Information** 

| Device      | Device Package | Marking     |  |
|-------------|----------------|-------------|--|
| NCE60NF420D | TO-263-2L      | NCE60NF420D |  |



TO-263

V1.0

Table 1. Absolute Maximum Ratings (T<sub>c</sub>=25℃)

| Parameter  | Symbol                  | Value   | Unit |
|--|-------------------------|---------|------|
| Drain-Source Voltage (Vgs=0V)  | VDS                     | 600     | V    |
| Gate-Source Voltage (VDS=0V) ,AC (f>1 Hz)                                    | Vgs                     | ±30     | V    |
| Gate-Source Voltage (VDS=0V) ,DC   | Vgs                     | ±20     | V    |
| Continuous Drain Current at Tc=25°C  | I <sub>D (DC)</sub>     | 10      | А    |
| Continuous Drain Current at Tc=100°C   | I <sub>D (DC)</sub>     | 7       | Α    |
| Pulsed drain current (Note 1)  | I <sub>DM (pluse)</sub> | 30      | А    |
| Maximum Power Dissipation(Tc=25℃)  | P <sub>D</sub>          | 96      | W    |
| Derate above 25°C  |                         | 0.64    | W/°C |
| Single pulse avalanche current (Note 2)                                      | I <sub>AS</sub>         | 2       | А    |
| Reverse diode dv/dt, V <sub>DS</sub> ≤480 V,I <sub>SD</sub> <i<sub>D</i<sub> | dv/dt                   | 50      | V/ns |
| Drain Source voltage slope,V <sub>DS</sub> ≤480 V                            | dv/dt                   | 50      | V/ns |
| Operating Junction and Storage Temperature Range                             | $T_{J}, T_{STG}$        | -55+175 | °C   |



### **Table 2. Thermal Characteristic**

| Parameter   | Symbol            | Value | Unit  |
|---|-------------------|-------|-------|
| Thermal Resistance, Junction-to-Case (Maximum)    | R <sub>thJC</sub> | 1.56  | °C /W |
| Thermal Resistance, Junction-to-Ambient (Maximum) | R <sub>thJA</sub> | 62    | °C /W |

Table 3. Electrical Characteristics (TA=25<sup>o</sup>Cunless otherwise noted)

| Parameter                                | Symbol              | Condition  | Min | Тур  | Max  | Unit |
|--|---------------------|--|-----|------|------|------|
| On/off states                            |                     |  |     |      |      |      |
| Drain-Source Breakdown Voltage           | BV <sub>DSS</sub>   | V <sub>GS</sub> =0V I <sub>D</sub> =250uA        | 600 |      |      | V    |
| Zero Gate Voltage Drain Current(Tc=25°ℂ) | I <sub>DSS</sub>    | V <sub>DS</sub> =600V,V <sub>GS</sub> =0V        |     |      | 10   | μA   |
| Zero Gate Voltage Drain Current(Tc=125℃) | I <sub>DSS</sub>    | V <sub>DS</sub> =600V,V <sub>GS</sub> =0V        |     |      | 300  | μA   |
| Gate-Body Leakage Current                | I <sub>GSS</sub>    | V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V        |     |      | ±200 | nA   |
| Gate Threshold Voltage                   | V <sub>GS(th)</sub> | $V_{DS}=V_{GS},I_{D}=250uA$                      | 3.5 | 4.2  | 5    | V    |
| Drain-Source On-State Resistance         | R <sub>DS(ON)</sub> | V <sub>GS</sub> =10V, I <sub>D</sub> =5A         |     | 380  | 420  | mΩ   |
| Dynamic Characteristics                  |                     |  |     | '    |      |      |
| Gate Resistance                          | Rg                  | F=1MHZ, D-S short                                |     | 41   |      | Ω    |
| Input Capacitance                        | C <sub>iss</sub>    | ., 50,414 014                                    |     | 591  |      | pF   |
| Output Capacitance                       | Coss                | $V_{DS}$ =50V, $V_{GS}$ =0V,                     |     | 17   |      | pF   |
| Reverse Transfer Capacitance             | C <sub>rss</sub>    | F=1MHz   |     | 1.9  |      | pF   |
| Total Gate Charge                        | Qg                  |  |     | 13.7 | 15   | nC   |
| Gate-Source Charge                       | Q <sub>gs</sub>     | $V_{DS}$ =400 $V$ , $I_{D}$ =5 $A$ ,             |     | 3.3  |      | nC   |
| Gate-Drain Charge                        | Q <sub>gd</sub>     | V <sub>GS</sub> =10V                             |     | 6.9  |      | nC   |
| Gate plateau voltage                     | Vgp                 |  |     | 7.2  |      | V    |
| Switching times                          |                     |  |     |      |      |      |
| Turn-on Delay Time                       | t <sub>d(on)</sub>  |  |     | 16   |      | nS   |
| Turn-on Rise Time                        | tr                  | $V_{DD}$ =380 $V$ , $I_{D}$ =5 $A$ ,             |     | 12   |      | nS   |
| Turn-Off Delay Time                      | t <sub>d(off)</sub> | $R_G$ =4 $\Omega$ , $V_{GS}$ =10 $V$             |     | 50   |      | nS   |
| Turn-Off Fall Time                       | t <sub>f</sub>      |  |     | 9    |      | nS   |
| Source- Drain Diode Characteristics      |                     |  |     |      |      |      |
| Source-drain current(Body Diode)         | I <sub>SD</sub>     | T 05°0   |     |      | 10   | Α    |
| Pulsed-Source-drain current(Body Diode)  | I <sub>SDM</sub>    | T <sub>C</sub> =25°C                             |     |      | 30   | Α    |
| Forward on voltage                       | V <sub>SD</sub>     | Tj=25°C,I <sub>SD</sub> =10A,V <sub>GS</sub> =0V |     | 1.0  | 1.2  | V    |
| Reverse Recovery Time                    | t <sub>rr</sub>     |  |     | 80   |      | nS   |
| Reverse Recovery Charge                  | Q <sub>rr</sub>     | Tj=25°C,I <sub>F=</sub> 5A,                      |     | 0.24 |      | uC   |
| Peak reverse recovery current            | I <sub>rrm</sub>    | di/dt=100A/µs                                    |     | 6    |      | Α    |

Notes: 1. Repetitive Rating: Pulse width limited by maximum junction temperature

2. Tj=25  $^{\circ}\text{C}$  ,VDD=50V,VG=10V, RG=25 $\Omega$ 



## TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS (curves)

Figure 1. Safe operating area

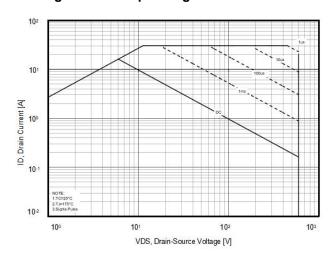


Figure 2. Source-Drain Diode Forward Voltage

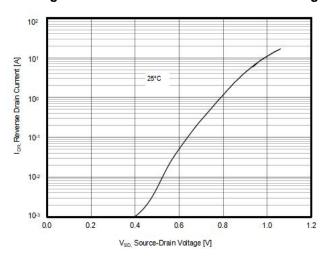


Figure 3. Transfer characteristics

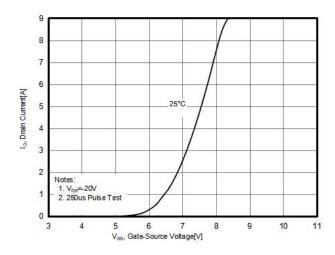


Figure 4. Output characteristics

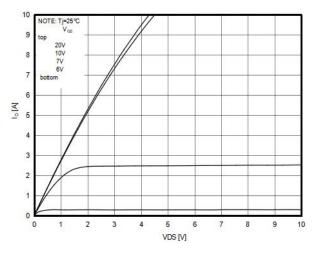


Figure 5. Static drain-source on resistance

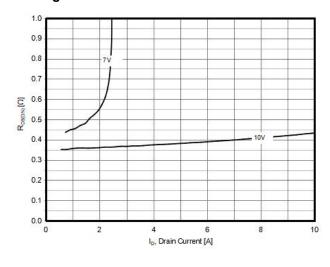
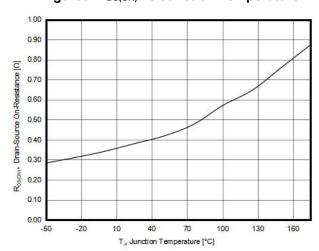


Figure 6. RDS(ON) vs Junction Temperature



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Figure 7. BV<sub>DSS</sub> vs Junction Temperature

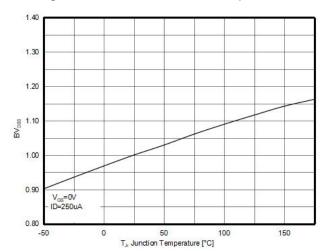


Figure 8. Maximum ID vs Junction Temperature

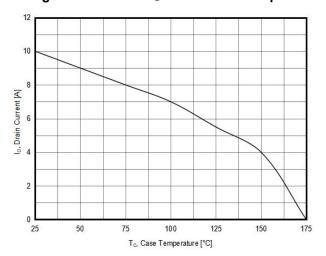


Figure 9. Gate charge waveforms

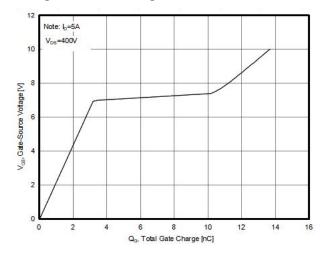
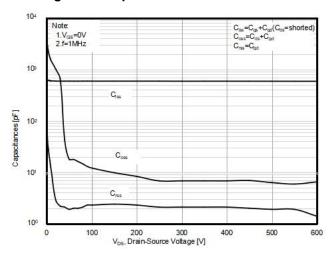


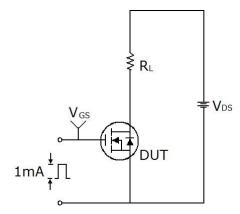
Figure 10. Capacitance

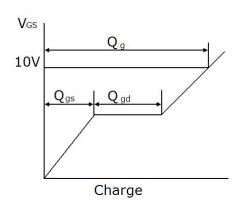




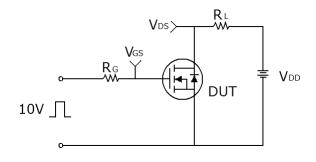
## **Test circuit**

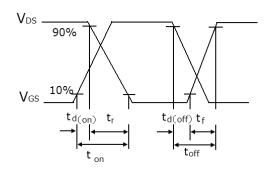
## 1) Gate charge test circuit & Waveform



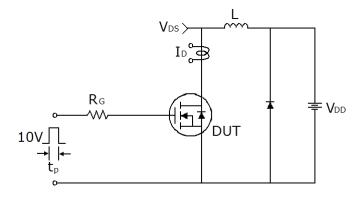


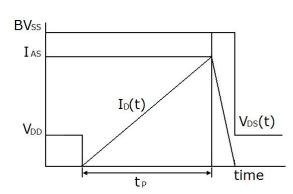
## 2) Switch Time Test Circuit:





## 3) Unclamped Inductive Switching Test Circuit & Waveforms

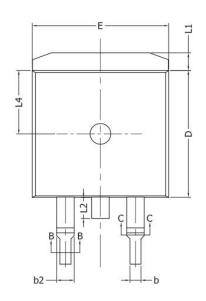


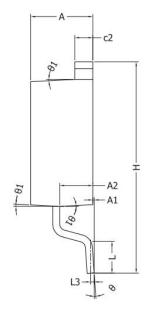


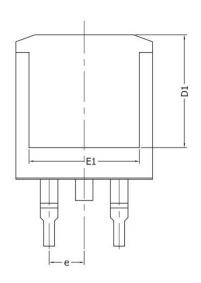
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# **TO-263-2L-P** Package Information



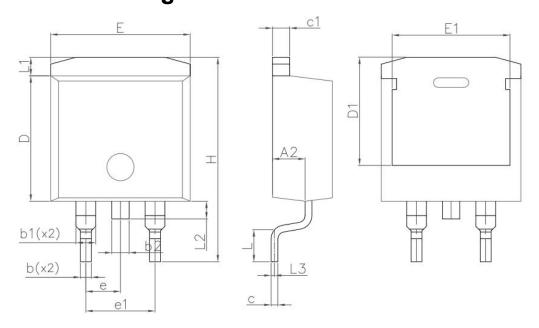




| Symbol | Dimensions | s In Millimeters | Dimensions In Inches |       |      |
|--------|------------|------------------|----------------------|-------|------|
| Symbol | Min.       | Max.             | Min.                 | Max.  |      |
| Α      | 4.40       | 4.60             | 0.173                | 0.181 |      |
| A1     | 0.00       | 0.25             | 0.000                | 0.010 |      |
| A2     | 2.20       | 2.60             | 0.087                | 0.102 |      |
| b      | 0.76       | 0.89             | 0.030                | 0.035 |      |
| b1     | 0.75       | 0.85             | 0.030                | 0.033 |      |
| b2     | 1.23       | 1.37             | 0.048                | 0.054 |      |
| b3     | 1.22       | 1.32             | 0.048                | 0.052 |      |
| С      | 0.47       | 0.60             | 0.019                | 0.024 |      |
| c1     | 0.46       | 0.56             | 0.018                | 0.022 |      |
| c2     | 1.25       | 1.35             | 0.049                | 0.053 |      |
| D      | 9.10       | 9.30             | 0.358                | 0.366 |      |
| D1     | 8.00       |                  | 0.315                |       |      |
| E      | 9.80       | 10.00            | 0.386                | 0.394 |      |
| E1     | 7.80       |                  | 0.307                |       |      |
| е      | 2.5        | 4BSC             | 0.100                | BSC   |      |
| Н      | 14.90      | 15.70            | 0.587                | 0.618 |      |
| L      | 2.00       | 2.60             | 0.079                | 0.102 |      |
| L1     | 1.17       | 1.40             | 0.046                | 0.055 |      |
| L2     |            | 1.75             |                      | 0.069 |      |
| L3     | 0.25BSC    |                  | 0.101BSC             |       |      |
| L4     | 4.60REF    |                  | L4 4.60REF 0.181REF  |       | 1REF |



# **TO-263-2L-E** Package Information



| Symbol | Dimensions | In Millimeters   | Dimensions In Inches |         |  |     |
|--------|------------|------------------|----------------------|---------|--|-----|
| Cymbol | Min.       | Max.             | Min.                 | Max.    |  |     |
| A2     | 4.20       | 4.60             | 0.165                | 0.181   |  |     |
| b      | 0.70       | 0.90             | 0.028                | 0.035   |  |     |
| b1     | 1.20       | 1.75             | 0.047                | 0.069   |  |     |
| b2     | 1.17       | 1.37             | 0.046                | 0.054   |  |     |
| С      | 0.40       | 0.60             | 0.016                | 0.024   |  |     |
| c1     | 1.15       | 1.40             | 0.045                | 0.055   |  |     |
| D      | 9.10       | 9.30             | 0.358                | 0.366   |  |     |
| D1     | 7.63       | 8.23             | 0.300                | 0.324   |  |     |
| E      | 10.05      | 10.45            | 0.396                | 0.411   |  |     |
| E1     | 8.35       | 8.95             | 0.329                | 0.352   |  |     |
| е      | 2.54       | 2.54BSC          |                      | BSC     |  |     |
| e1     | 5.08       | 5.08BSC          |                      | BSC     |  |     |
| Н      | 14.61      | 15.88            | 0.575                | 0.625   |  |     |
| L      | 1.78       | 2.79             | 0.070                | 0.110   |  |     |
| L1     | 1.36       | 1.36REF          |                      | IREF    |  |     |
| L2     | 1.30       | 1.30REF 0.051REF |                      | 1.30REF |  | REF |



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